



Radiation Effects in Linear Accelerator Operations for Non Destructive Testing, Security, Industrial and Medical Applications

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Outline for Today

- Varian Medical Systems who we are and what do we do?
- More Sophisticated Treatments Require more computer control - More CPUs, FPGAs, SRAM and DRAM
- Susceptibility of X-rays and Neutrons
- Testing is Critical
- What does a User Need

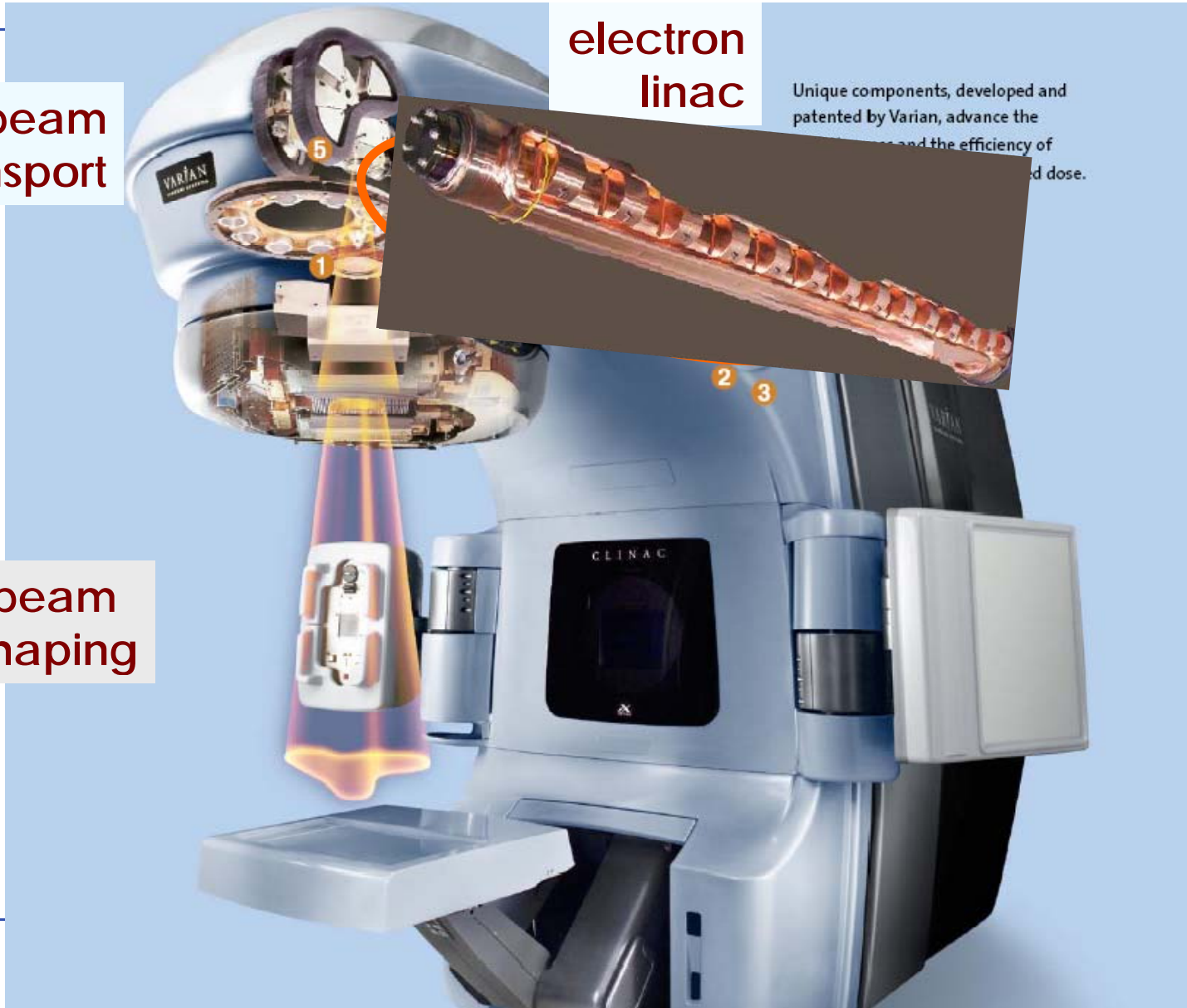
Medical Accelerators for Photons or Electrons

beam transport

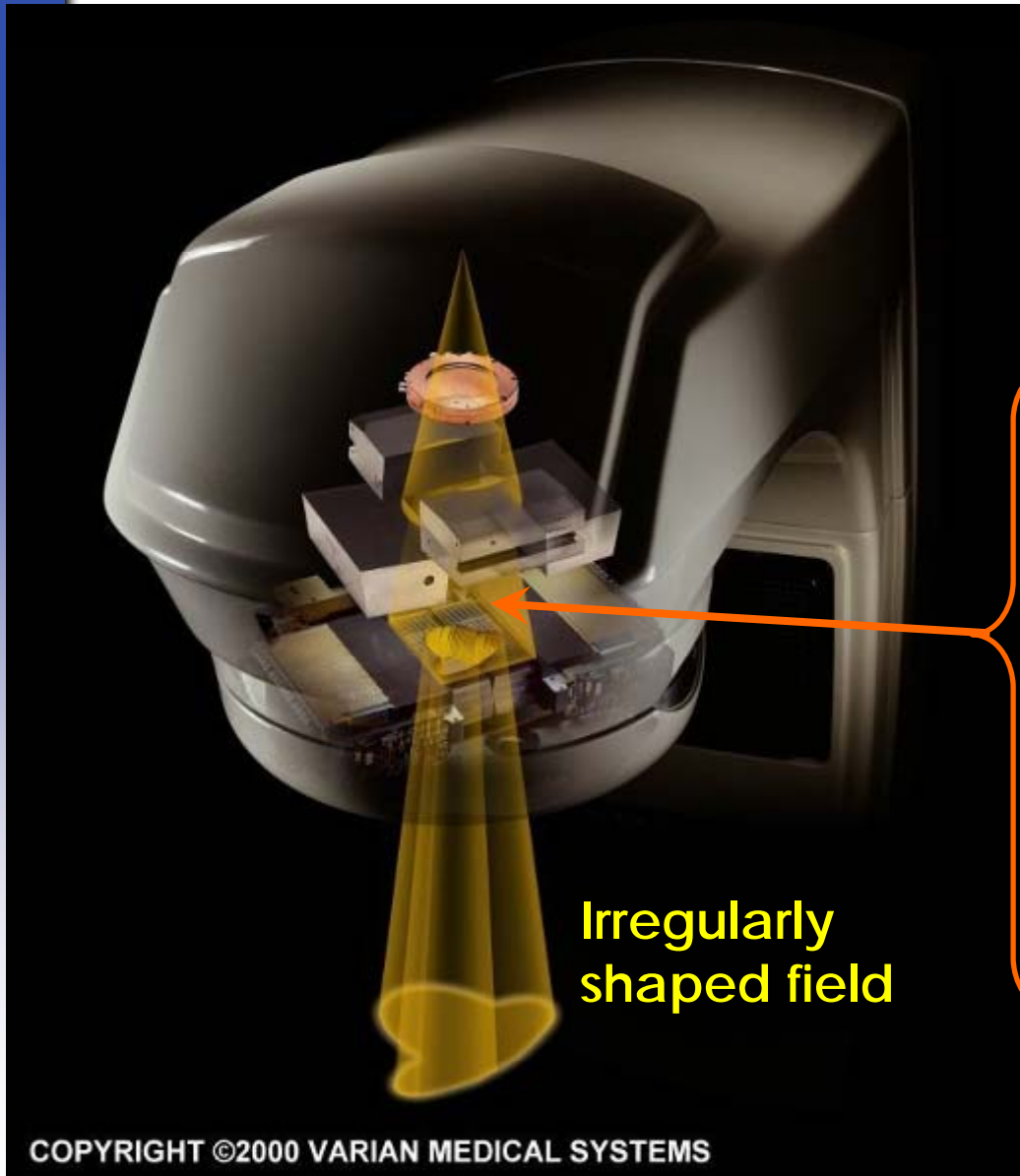
electron linac

Unique components, developed and patented by Varian, advance the and the efficiency of dose.

beam shaping



Multi-Leaf Collimator (MLC)



Fine beam collimation

Because tumors don't have corners



120 tungsten "leaves"

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Millennium MLC: SomaVision™ and VARiS®

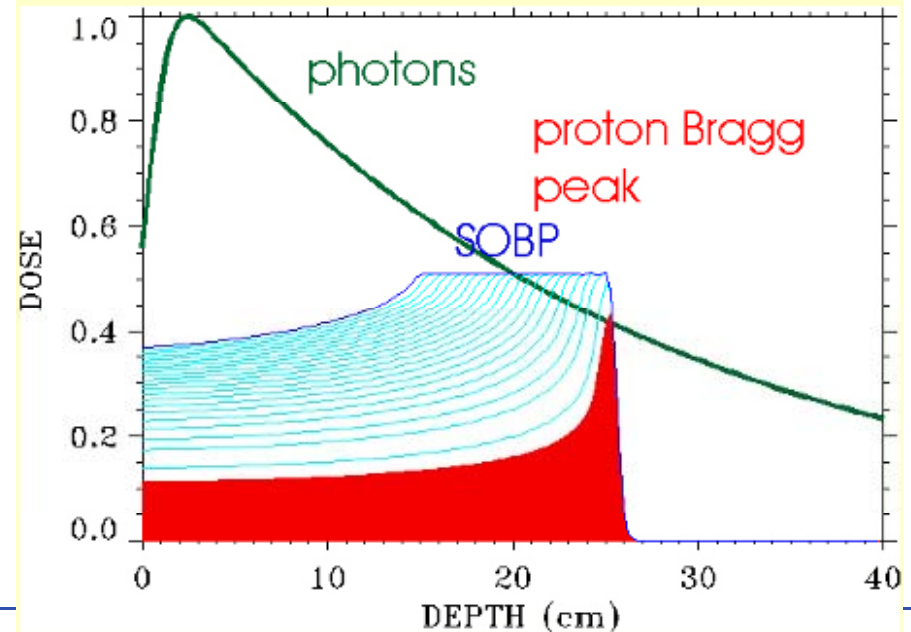
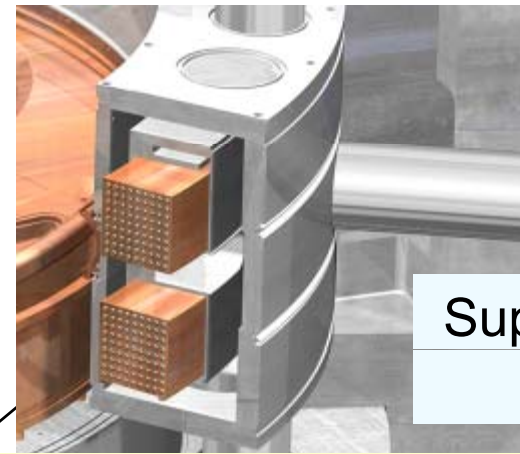
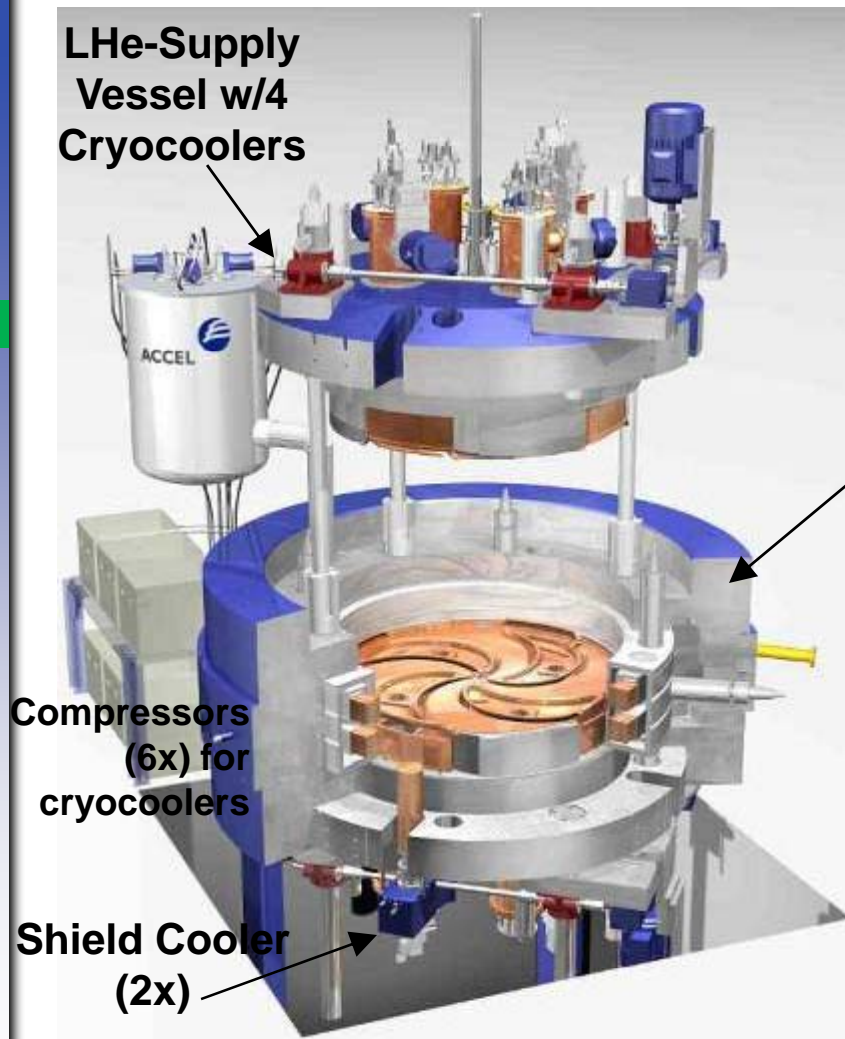
VARIAN
medical systems

Ginzton Technology Center

Medical Accelerators for Proton Therapy

VMS 250 MeV Isochronous Superconducting Proton Cyclotron

(USA FDA 510 k pending)



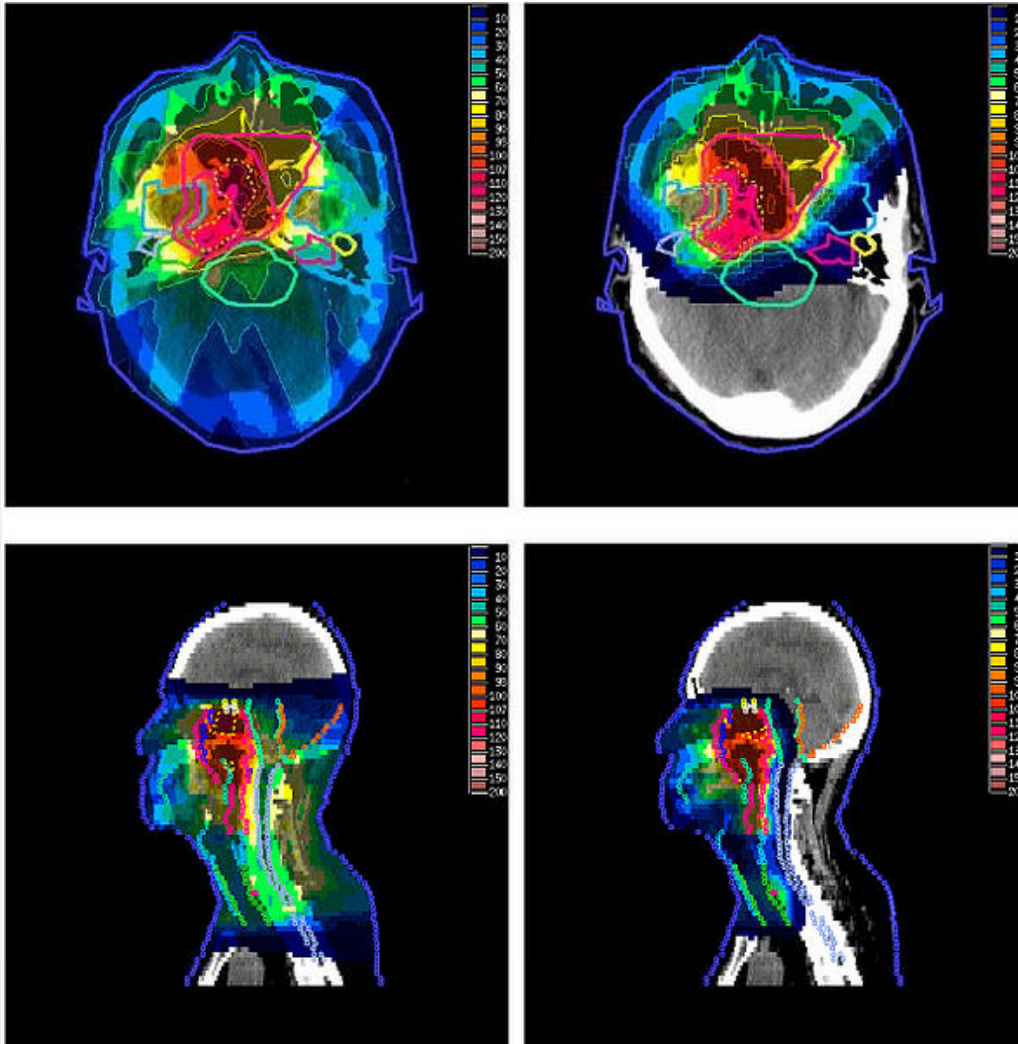
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medical systems

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Advantages of Proton Treatment - Healthy Tissue and Critical Structures Spared

(USA FDA 510 k pending)



Taheri-Kadkhoda et al.
Radiation Oncology 2008 3:4
doi:10.1186/1748-717X-3-4

Irradiation of [nasopharyngeal carcinoma](#) by photon(X-ray) therapy (left) and proton therapy (right).

Homeland Security Cargo Screening

A Growing need for accelerators

Mobile Platforms

Smiths Detection
 Rapiscan Systems
 L3



2-6.0 MeV
 0.2 -3.5
 cGy/min
 350+ mm Steel



Gantry Systems

Smiths Detection 3-6 MeV
 Rapiscan Systems 0.3-8 cGy/min
 L3 350 mm+ Steel
 Varian

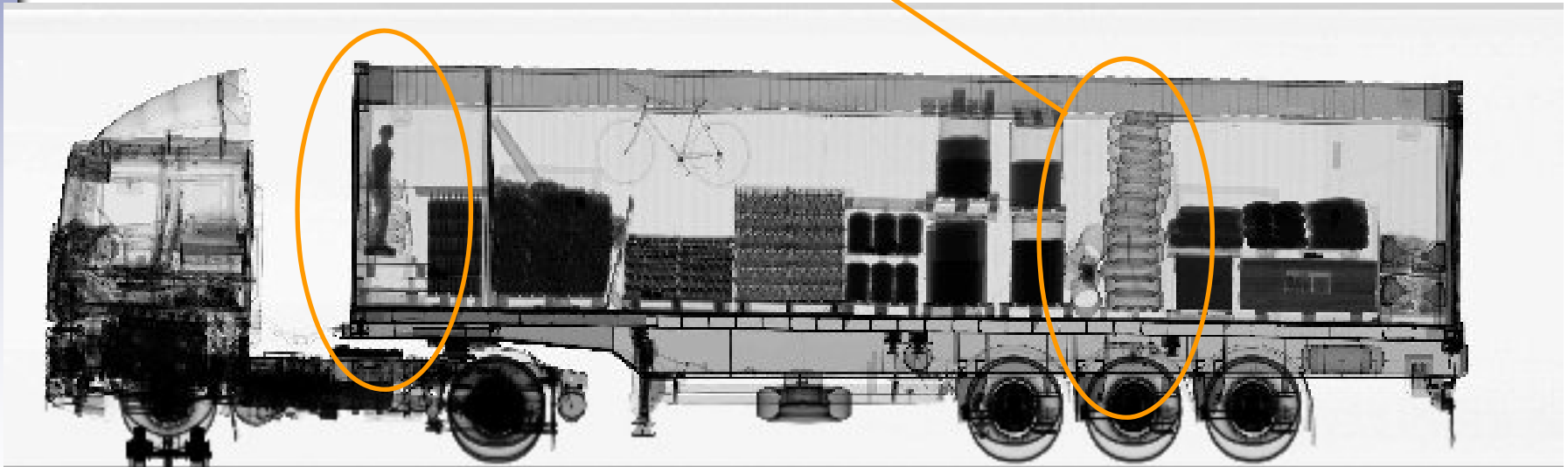
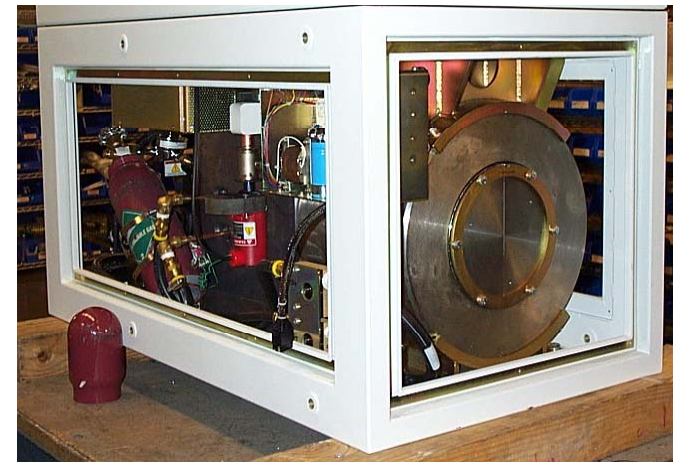
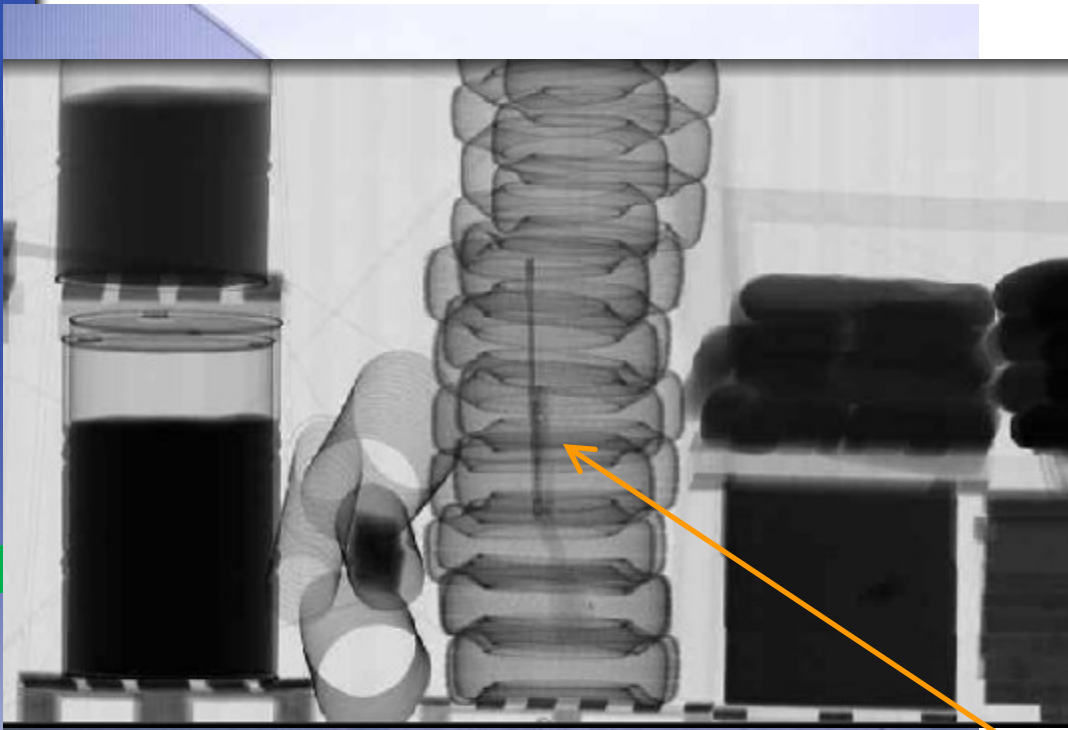
Fixed Sites

Smiths Detection
 Rapiscan Systems
 L3
 IHI
 MHI

6- 9 MeV
 10-30 cGy/min
 400+ mm in Steel

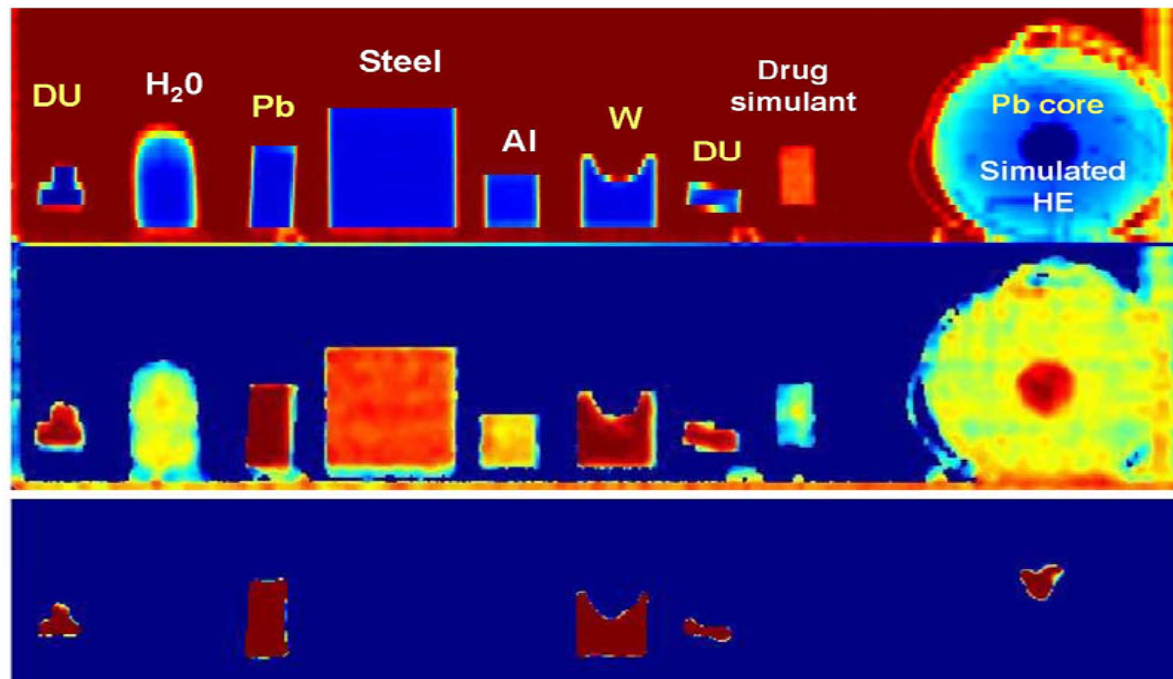


X-ray Systems



Dual Energy X-ray Systems for Contraband Detection

CAARS Candidate Technologies (continued)



TODAY: 6MeV Radiograph

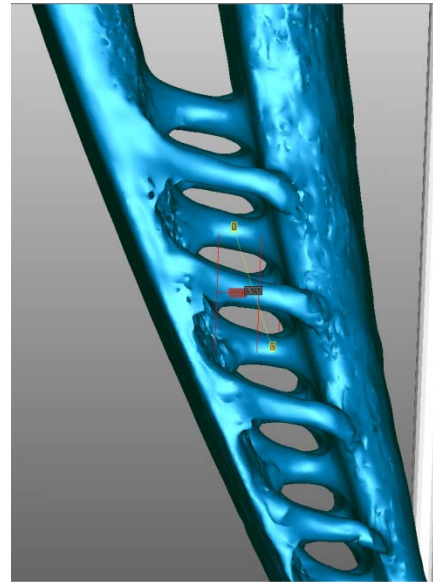
CAARS:
Automated Z-Map formed with 6 & 9 MeV scans
Red = High-Z
Yellow/Green = Low-Z

Automatic Alert on High Density Materials

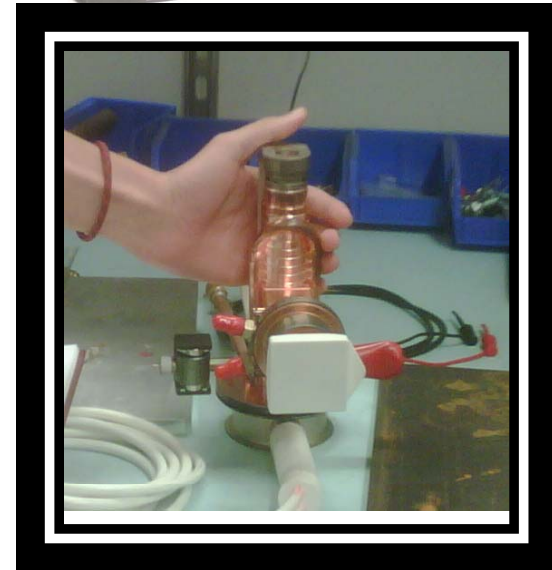
Klystron
Driven
Dual
Energy
Linac
E= 6-9
MeV
Rep Rate
400 Hz

Accelerators for NDT

- Mega-Voltage Computed Tomography (CT)
- Digital Radiography



X-band 1
MV



Amorphous silicon devices

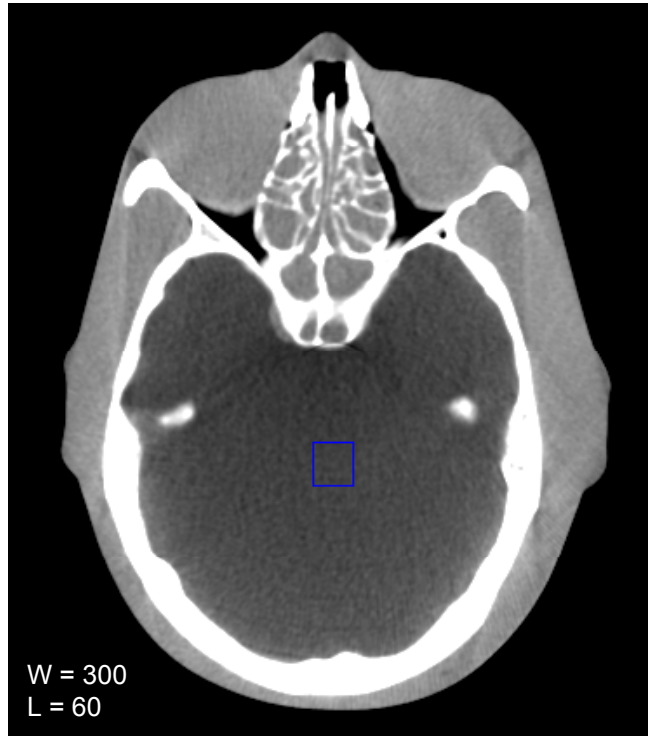
■ Device physics

- a-Si has significant atomic disorder vs. crystalline silicon (c-Si)
- Film contains ~ 10% atomic hydrogen → a-Si:H
- Conduction is by trap and release transport
- Has poor electron drift mobility (μ_d)
 - a-Si $\mu_d \sim 1 \text{ cm}^2/\text{Vsec}$ and $\ll\ll$ for holes
 - c-Si $\mu_d \sim 1,500 \text{ cm}^2/\text{Vsec}$
- P-i-n photodiode fabricated with:
 - 1 μm intrinsic i-layer between 10 nm p+ and n+ layers
 - Has an optical band gap ~ 1.8 eV
 - Spectral quantum conversion efficiency ~ 80% for light 500–600 nm
- Thin film transistors (TFT) fabricated as N-channel devices with:
 - 100K to 4M ohm on-resistance
 - 10^{15} ohm off-resistance

■ Radiation tolerance

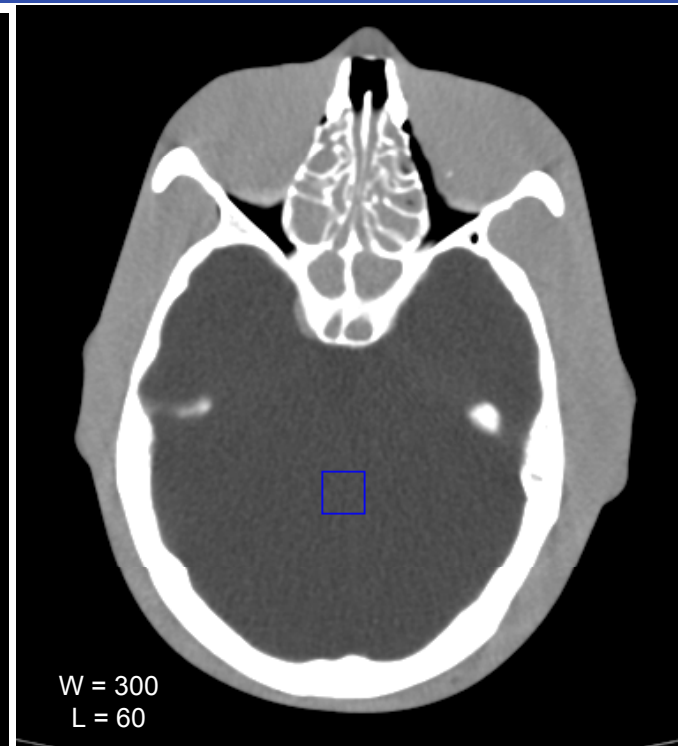
- a-Si > 1 M rad gamma ray dose from random defect structure and self annealing at room temp
- c-Si ~ 10 K rad gamma ray dose

Strip Detector MDCT Comparison



FP MDCT 64-row

Tech: 120 kV, 375 mAs, 1.5 sec
3 mm slice, 25 cm FOV
ROI = 2 HU, noise = 0.51 %



Diagnostic 16-slice scan PB

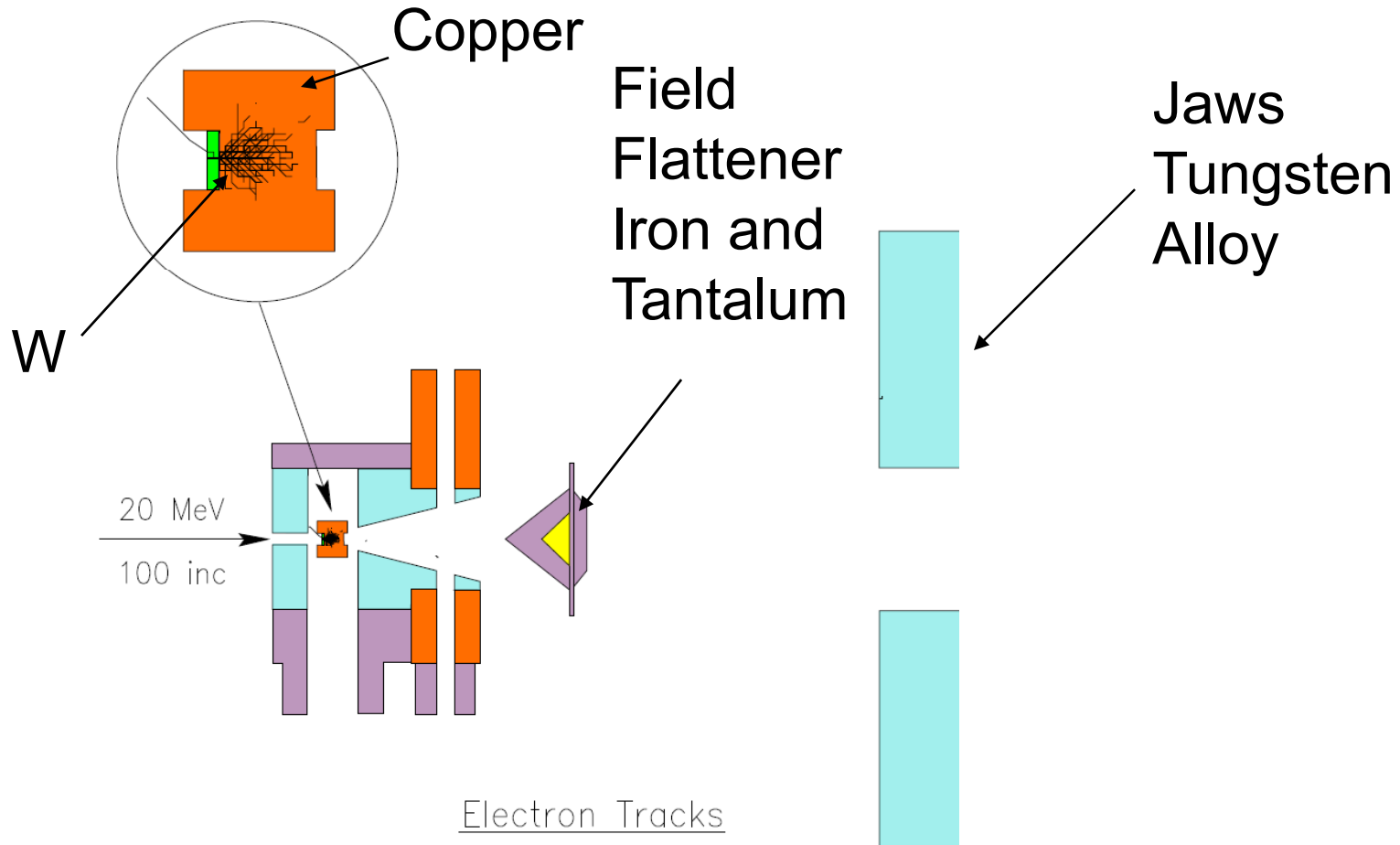
Tech: 120 kV, 400 mAs, 1.5 sec
3 mm slice, 25 cm FOV
ROI = 0 HU, noise = 0.44 %

Neutron Production in Linear Accelerators

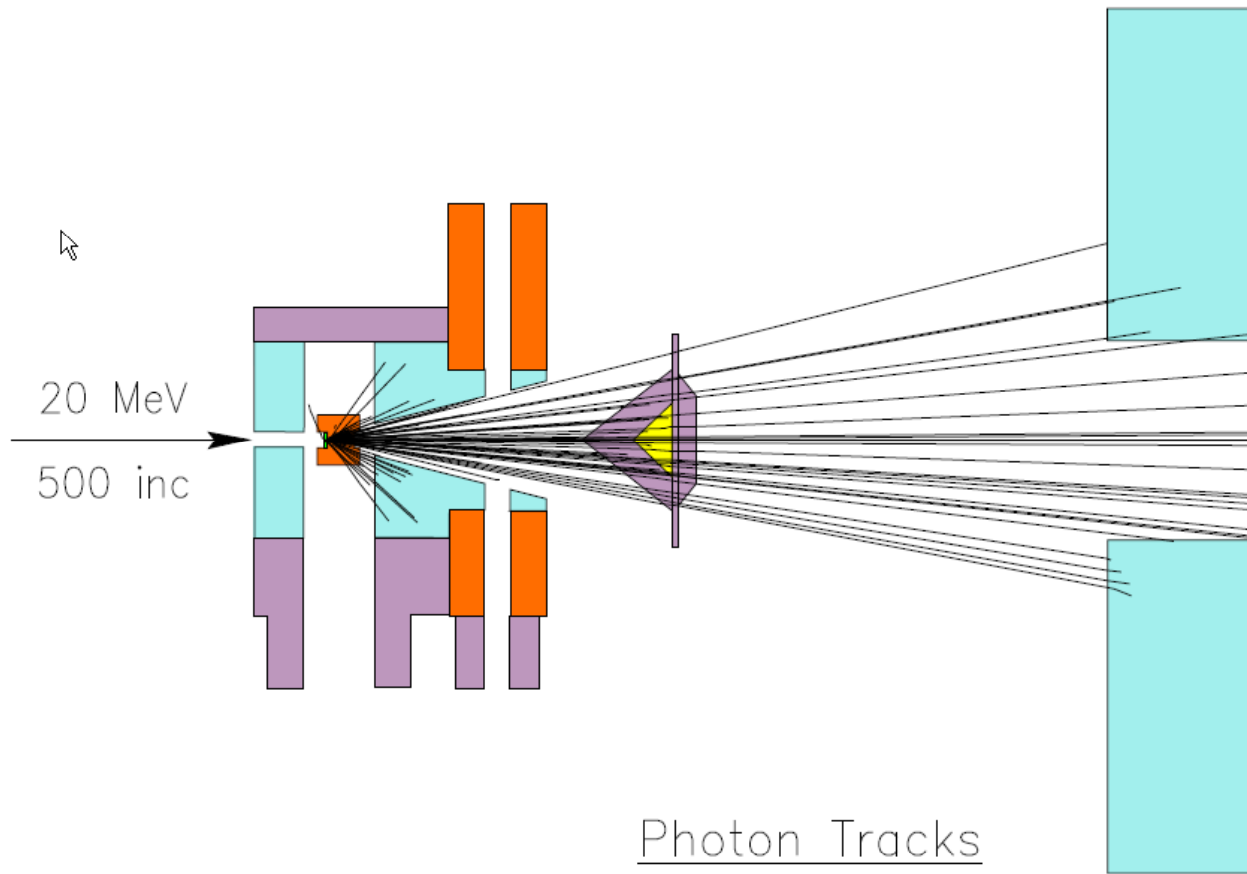
A Brief Primer

- Neutrons arise from (γ, n) reactions
 - Targets, Collimators, Field Flatteners and MLC
 - Threshold Energy for (γ, n) Dependent on Materials
 - Be 1.67 MeV
 - W 6.19 MeV
 - Cu is 9.91 MeV
 - Can be made in Electron Mode
 - The probability is small only $\sim 1\%$ of the photon rate

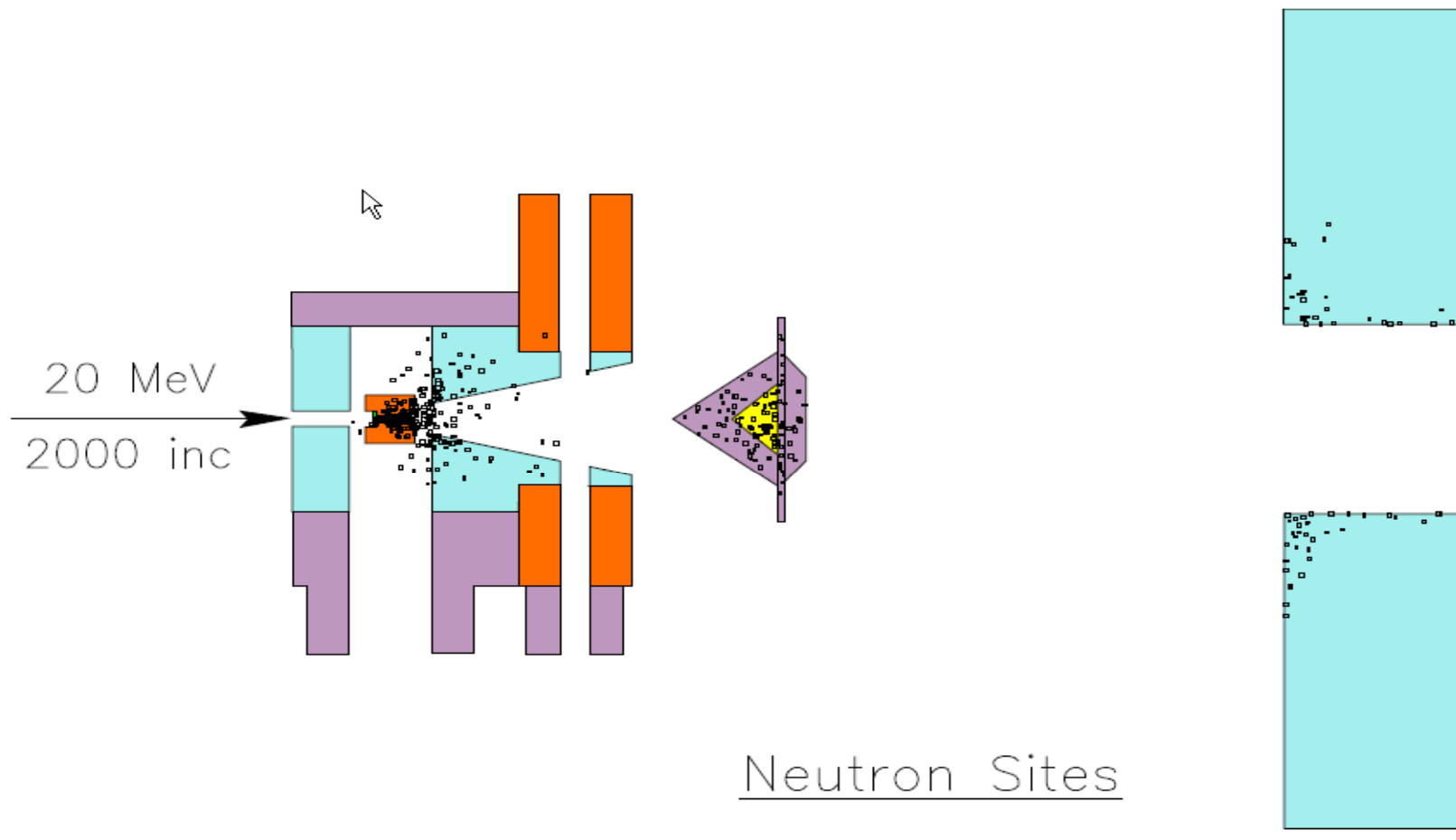
Electrons in the Target



Photons Created in the Target



Photoneutron Production from the Photons and Electrons



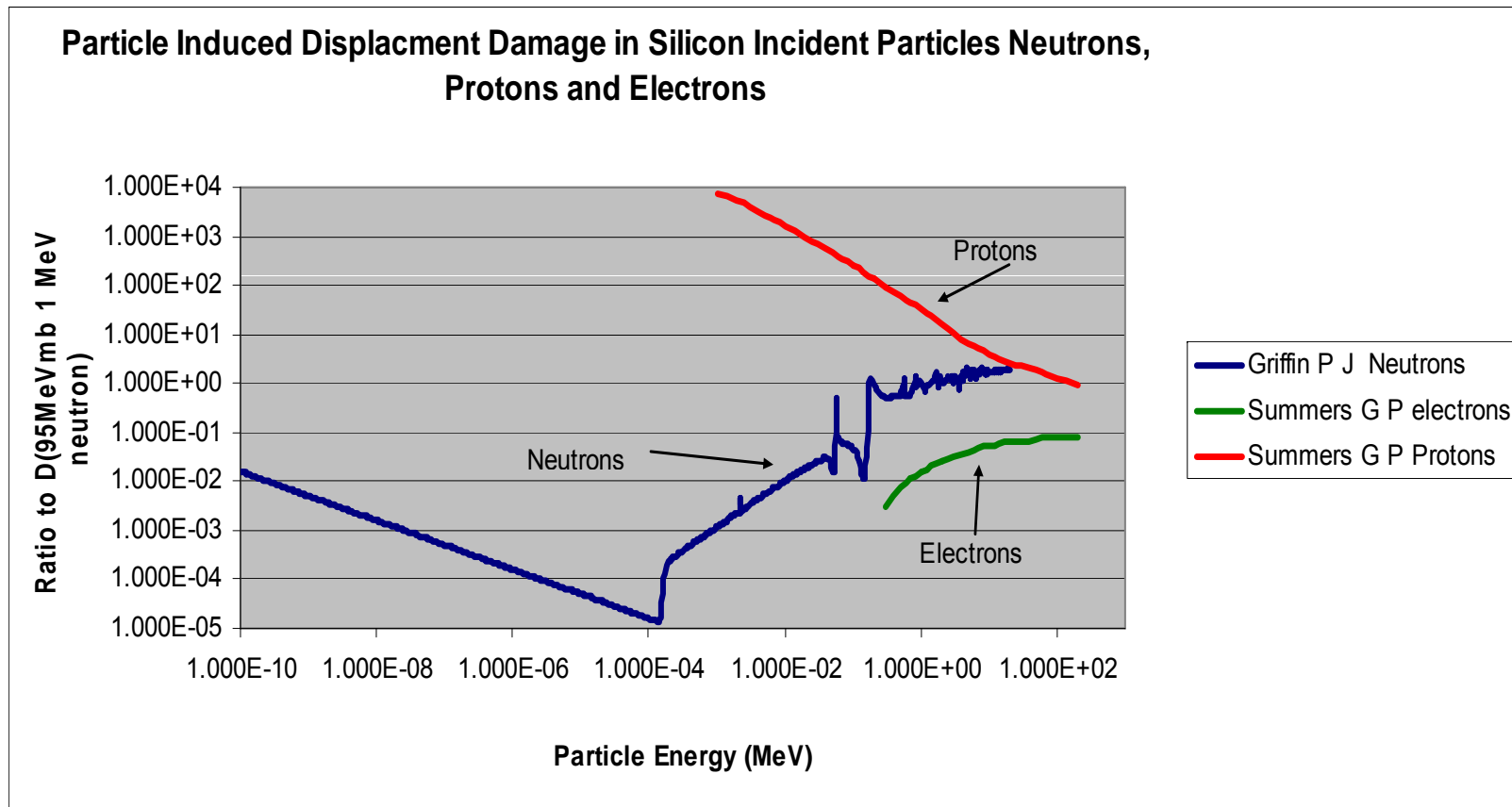
Why is this a Problem?

- Neutrons Induce Damage in Silicon Devices Two Ways
- First - Fast Neutrons can cause nuclear reactions in the chip leading to bit flips
 - (n, α) , (n, p) , and (n, d) are the possible nuclear reactions
 - Reaction thresholds are 2.75, 3.99, and 9.69 MeV respectively
- Second - The long term damage related to lattice dislocations, this is a Total Dose Exposure Issue

Definitions - What is the Damage Process

- SEU – Single Event Upset (Most Frequent)
 - Passage of a high energy particle through an electronic device that causes a change in the state of the device
 - Need to Reload Data to continue
- SEL - Single Event Latch-up (Less Frequent)
 - Power on and off - Hard Reset to recover
- SEB or SEGR – Single Event Burnout or Single Event Gate Rupture (Not Yet Observed on HET)
 - Complete Device Failure

Comparison of Particle Induced Damage in Silicon relative to the damage of a 1 MeV Neutron



IGBT Failure Due to a Neutron Induced SEB



Figure 1: Example of IGBT failure during recent acceptance tests.

- IGBT Switch Failure from Cosmic Ray Neutron
- SEB on the Klystron Modulator for the SNS Accelerator Facility at Oak Ridge National Laboratory

Neutron Spectra from Cosmic Rays at sea level and Mauna Kea

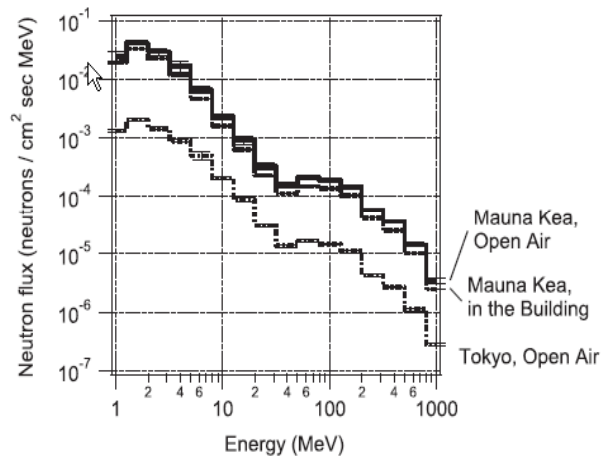


Fig. 3: Neutron energy spectra measured by Bonner multisphere spectrometer measured at the open air area and in the building of Subaru Telescope, and open air area of Tokyo.

of 10 cm for main detector. The main detector is

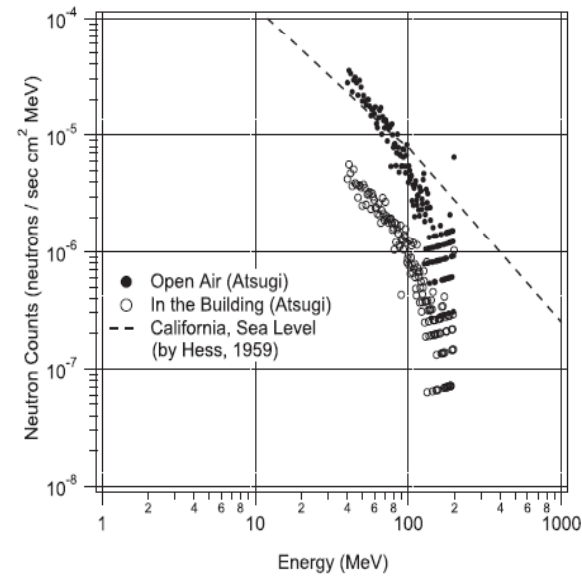


Fig. 4: Neutron energy spectra preliminary measured by scintillator spectrometer at Atsugi (Japan). Solid circles and open circles are measured at open air area and in the building, respectively. Dotted line indicates the spectrum reported by Hess et al. (1959) [1]

VMS at 15 MeV, 18 MeV, and 20 MeV

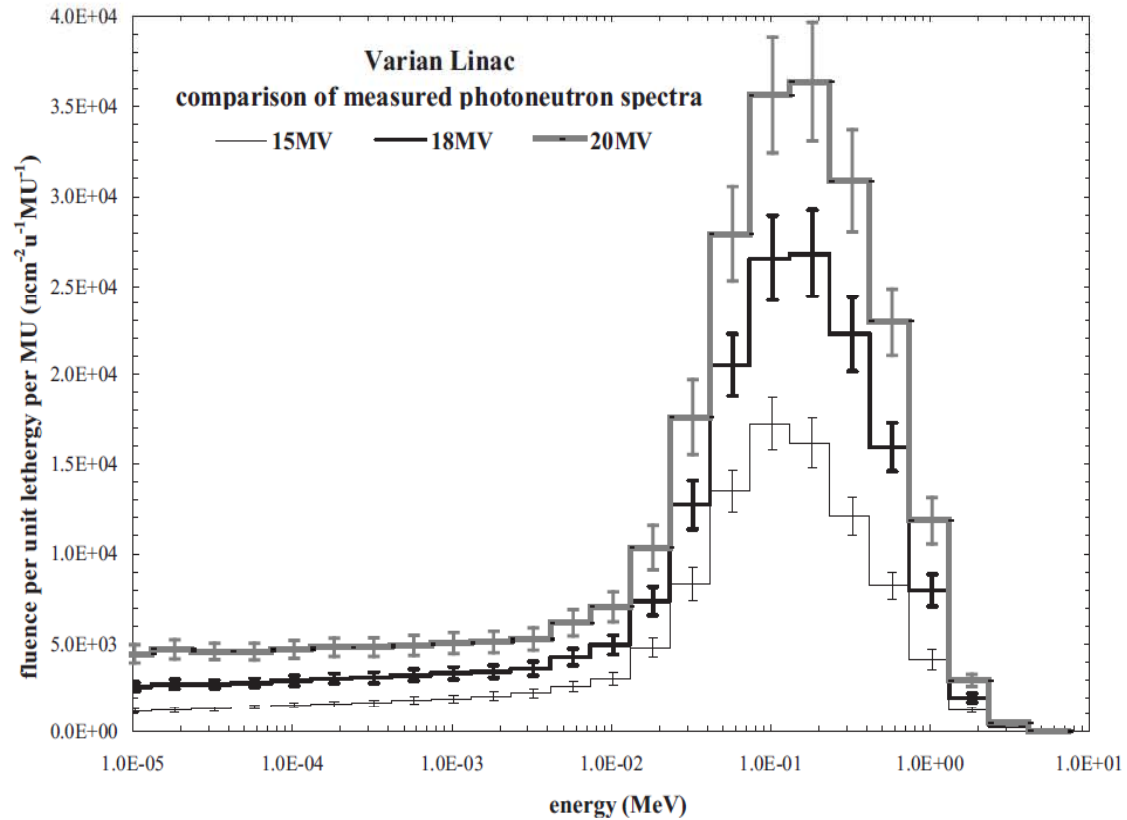


FIG. 7. Measured photoneutron spectra for Varian 21EX linacs with nominal photon beam energies of 15, 18, and 20 MV and the upper and lower jaws and MLC closed.

How do the Linac Photoneutron Rates compare to Cosmic Ray Fluence Rates at Sea Level?

- Compare the 3 MeV neutron rate for a VMS Clinac at 20X to Cosmic Ray Fluence at Sea Level (Tokyo, JP 35°40' N SF is 37° 46' N)
 - Clinac Rate is ~ **2.0 x 10⁶ higher**
- Initial VMS Measurements show a mean neutron energy of about 0.45 MeV
- Monte Carlo Calculations show a neutron spectrum out to ~16 MeV

Data Comparison of New and Old Data on VMS Systems

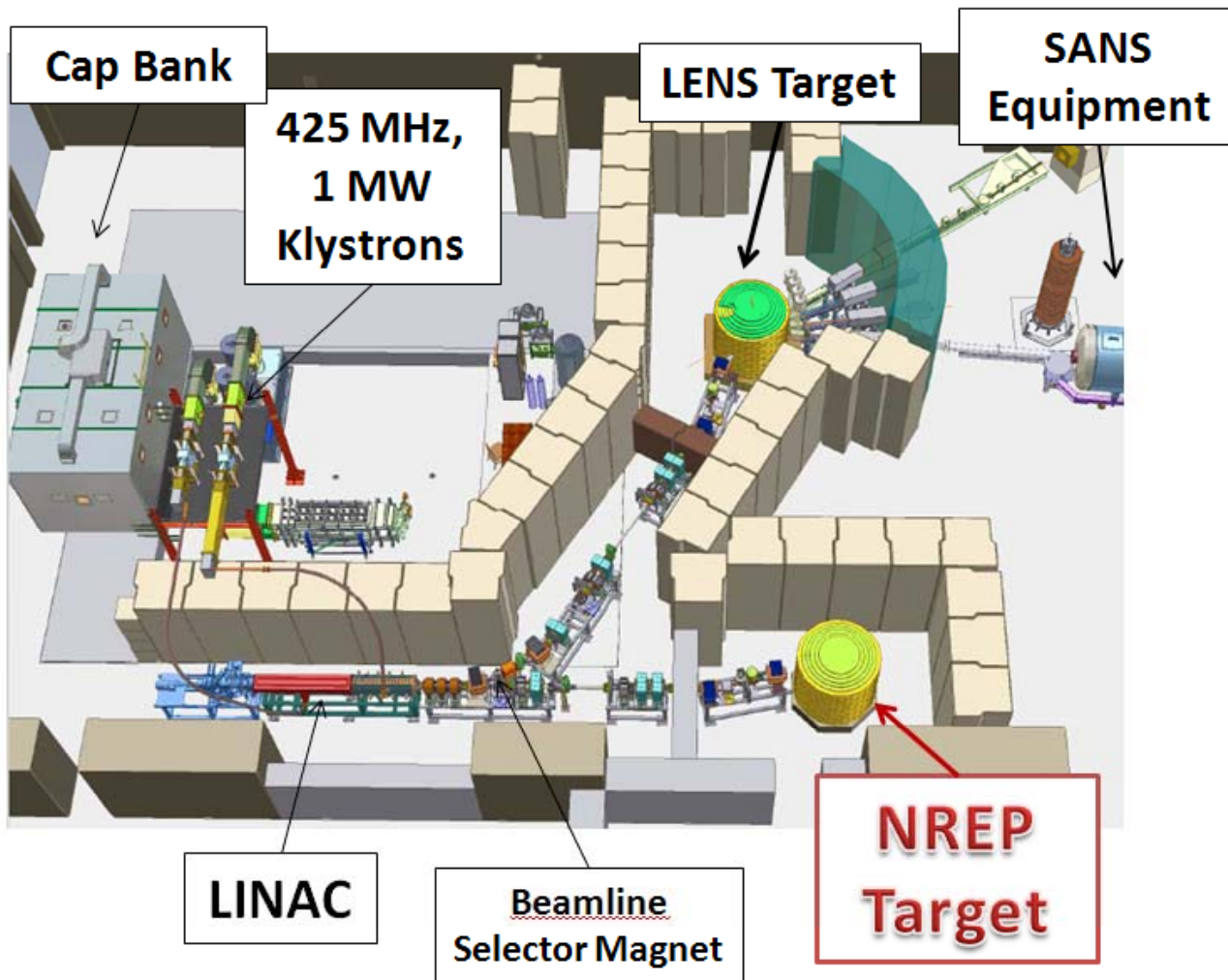
TABLE IV. Measured photoneutron data from the current study and previously reported measured and Monte Carlo calculated data for Varian linacs with 15, 18, and 20 MV photon beam energies.

Energy	Neutron fluence (n cm ⁻² MU ⁻¹)			Average energy (MeV)		
	Kase <i>et al.</i> ^a		Current study	Kase <i>et al.</i> ^a		Current study
	Calc.	Meas.	Meas.	Calc.	Meas.	Meas.
15	7.6 × 10 ⁴	5.3 × 10 ⁴	6.67 × 10 ⁴	0.3	0.19	0.23
18	1.4 × 10 ⁵	0.8 × 10 ⁵	1.18 × 10 ⁵	0.36	0.42	0.24
20	1.5 × 10 ⁵	1.1 × 10 ⁵	1.69 × 10 ⁵	0.36	0.29	0.24

^aReference 8.

Medical Physics, Vol. 36, No. 9, September 2009

Testing and Indiana University Low Energy Neutron System (LENS)

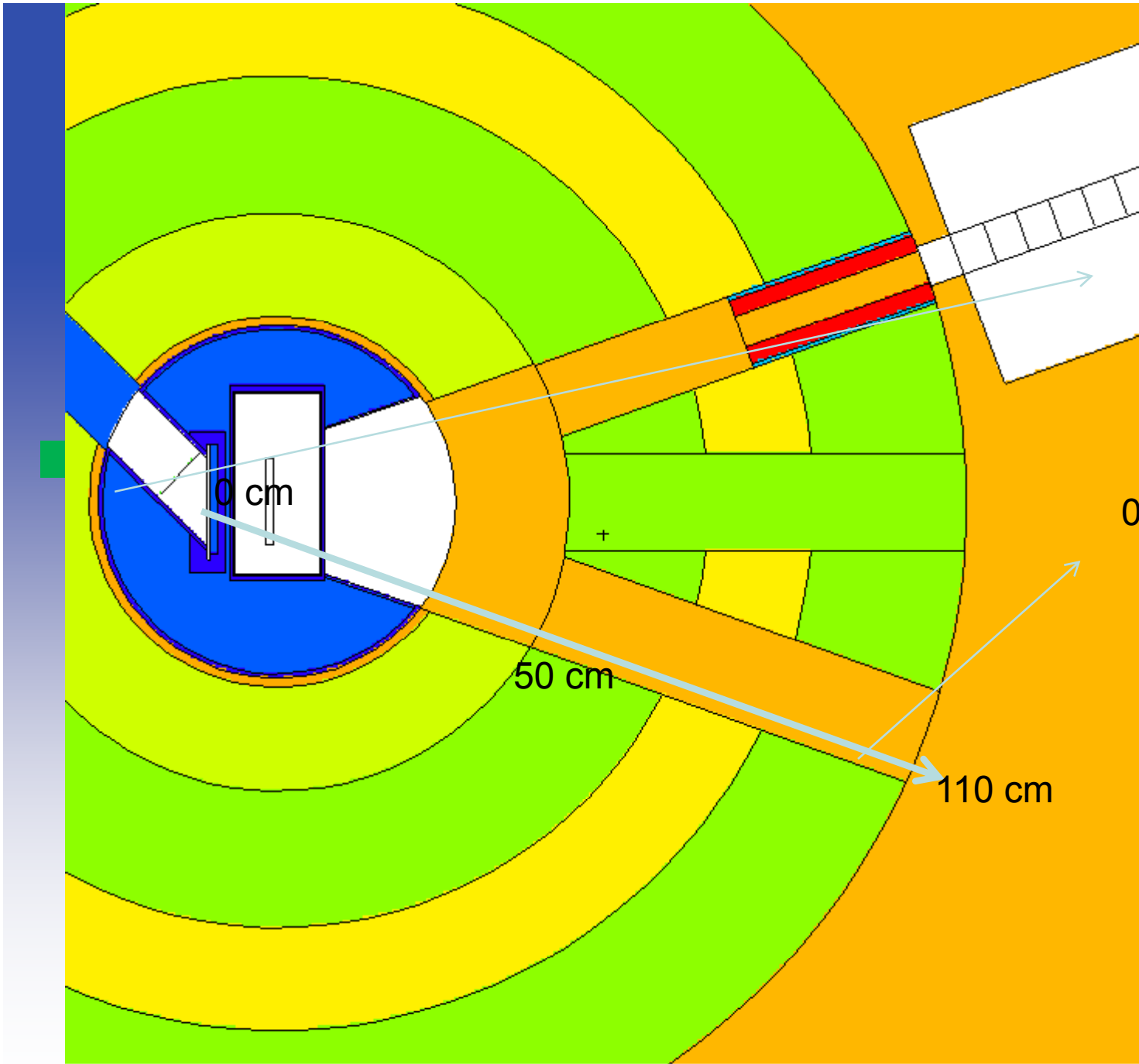


Reaction Channels Open for particle production

Open channels for the reaction:

$p + {}^9\text{Be}$ at 13.00 MeV

Reaction Products	Q-Value (MeV)	Threshold (MeV)
${}^{10}\text{B} + \gamma$	6.58585	0
${}^6\text{Li} + \alpha$	2.12535	0
$d + 2 \alpha$	0.65102	0
${}^8\text{Be} + d$	0.55918	0
${}^9\text{Be} + p$	0	0
$n + p + 2 \alpha$	-1.57357	1.74955
${}^8\text{Be} + n + p$	-1.66541	1.85166
${}^9\text{B} + n$	-1.85049	2.05743
${}^5\text{He} + p + \alpha$	-2.46358	2.73908
${}^5\text{Li} + n + \alpha$	-3.53859	3.93431
${}^7\text{Li} + {}^3\text{He}$	-11.20242	12.45517



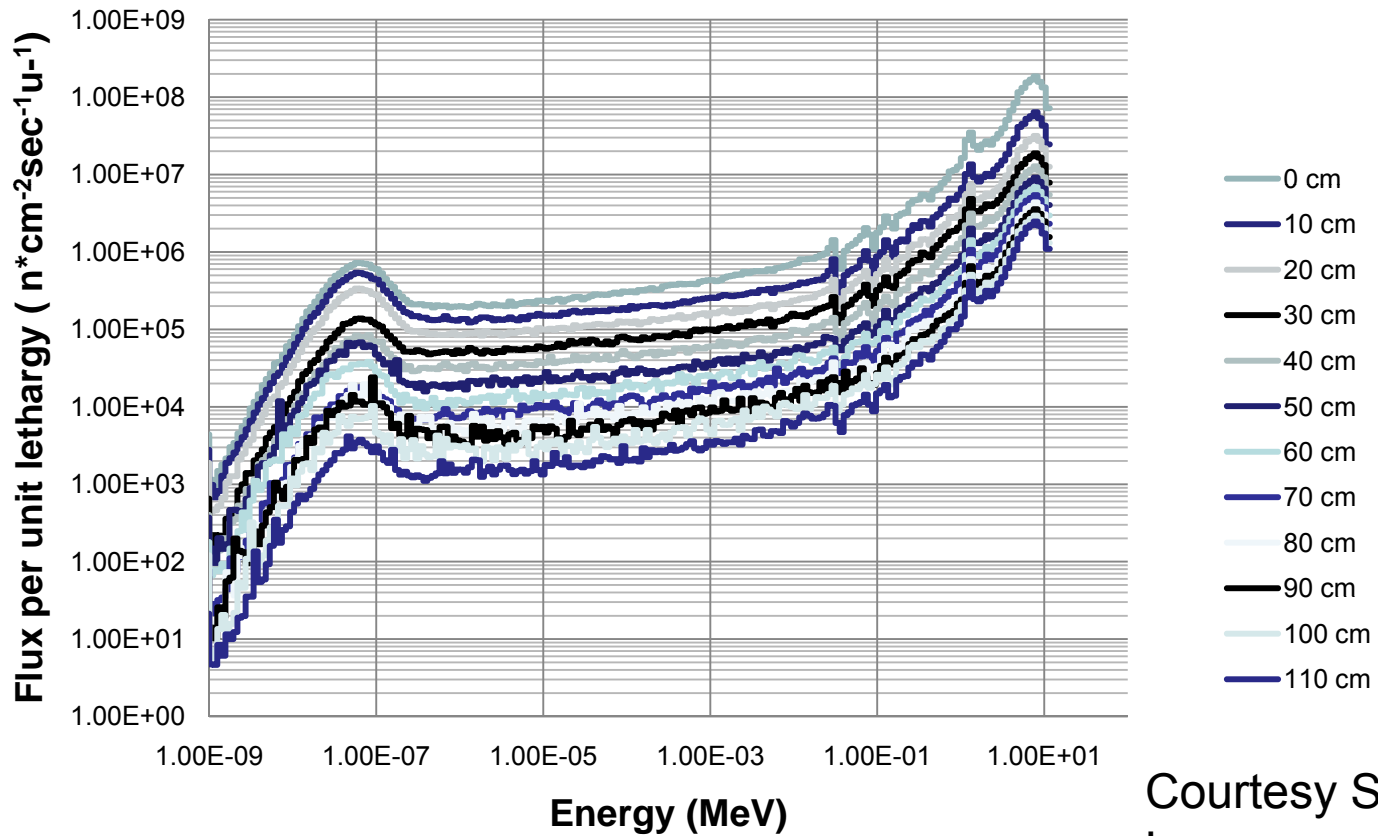
13 MeV 15mA 20Hz
400us proton beam
= 0.12mA , 1.56 Kw

0cm, 10 cm ~ 110 cm
Detector positions

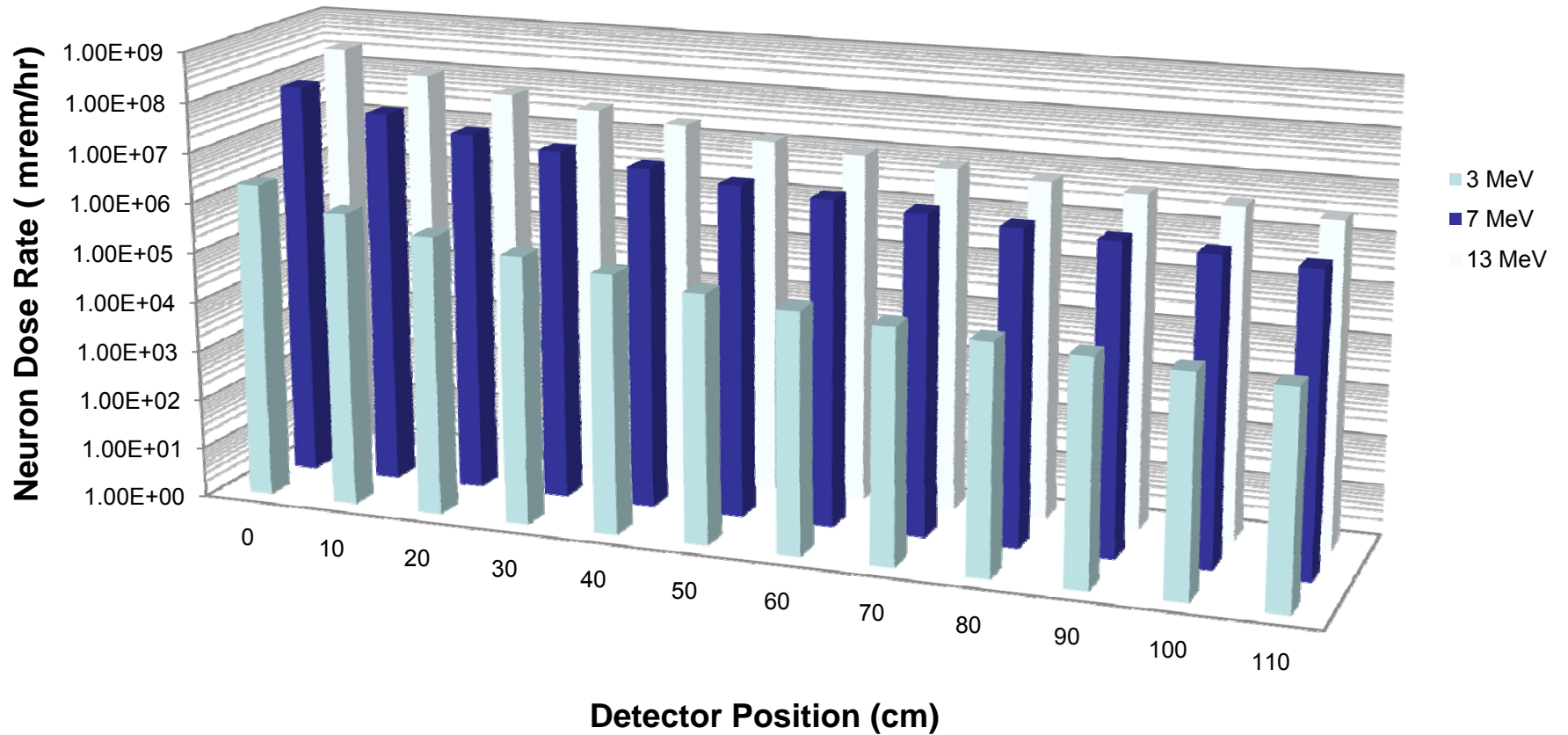
50 cm

110 cm

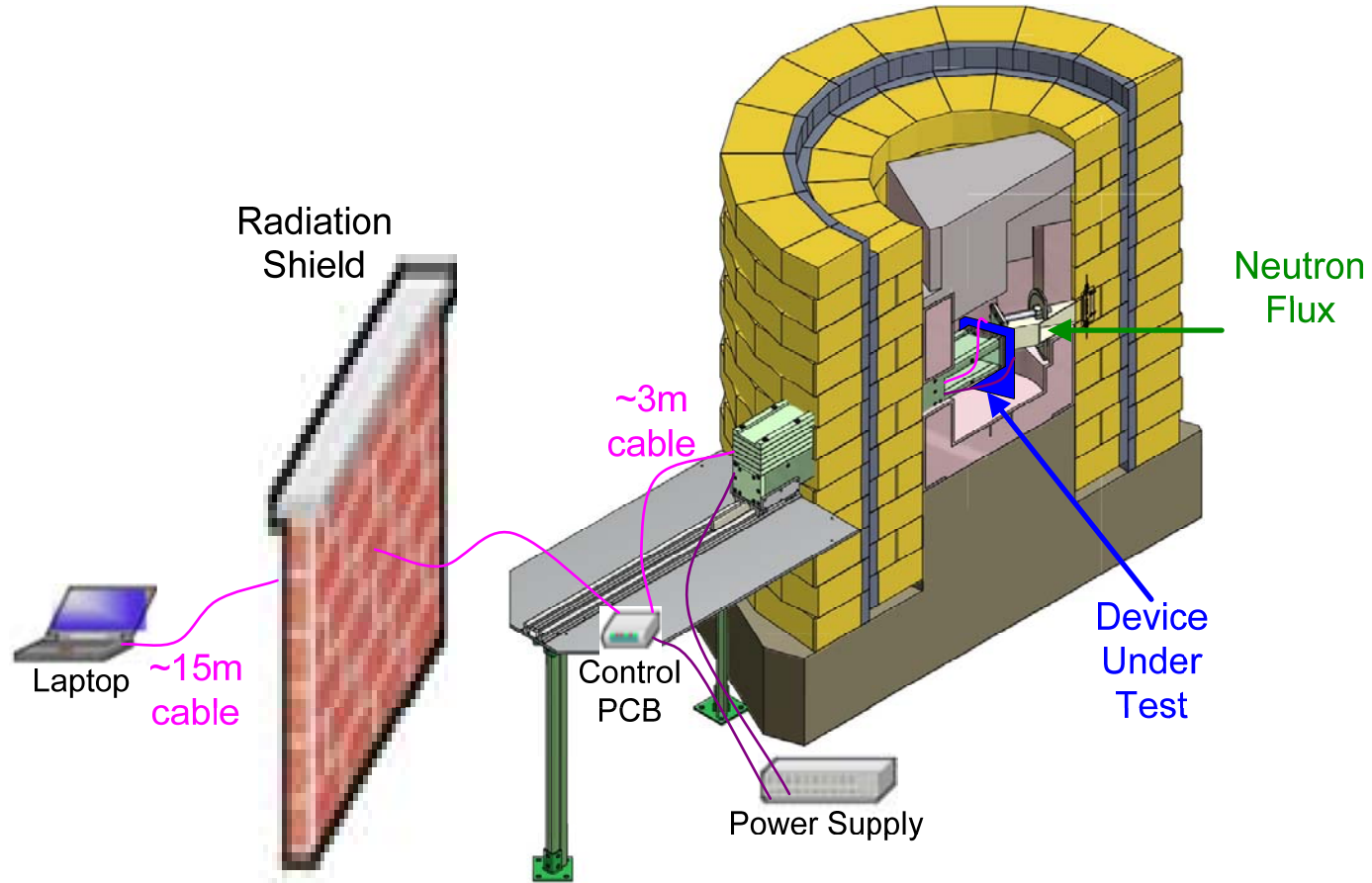
**Neutron Spectrum with 13MeV 15mA 20Hz 400us
proton beam**



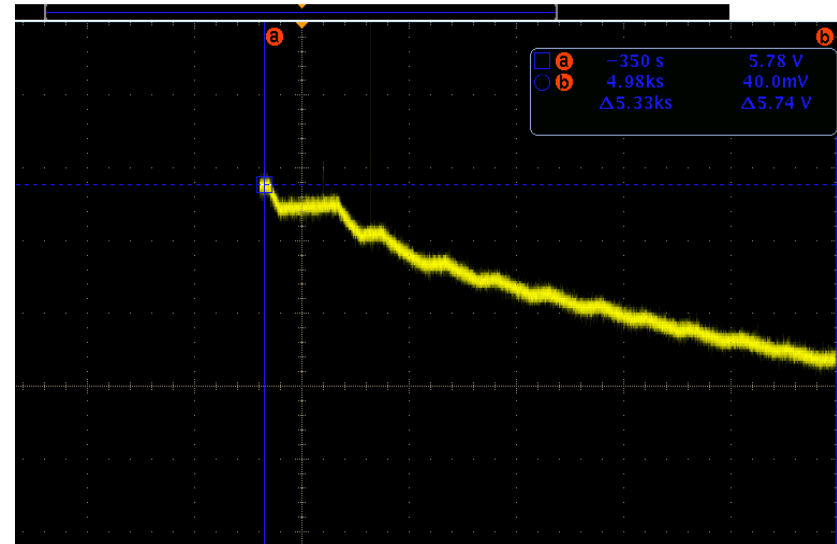
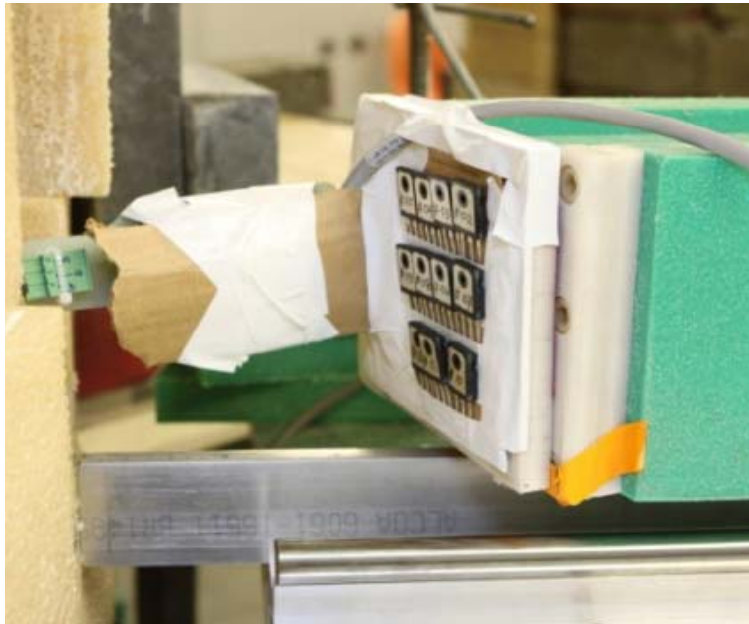
Courtesy Sangjin
Lee



Experimental Setup



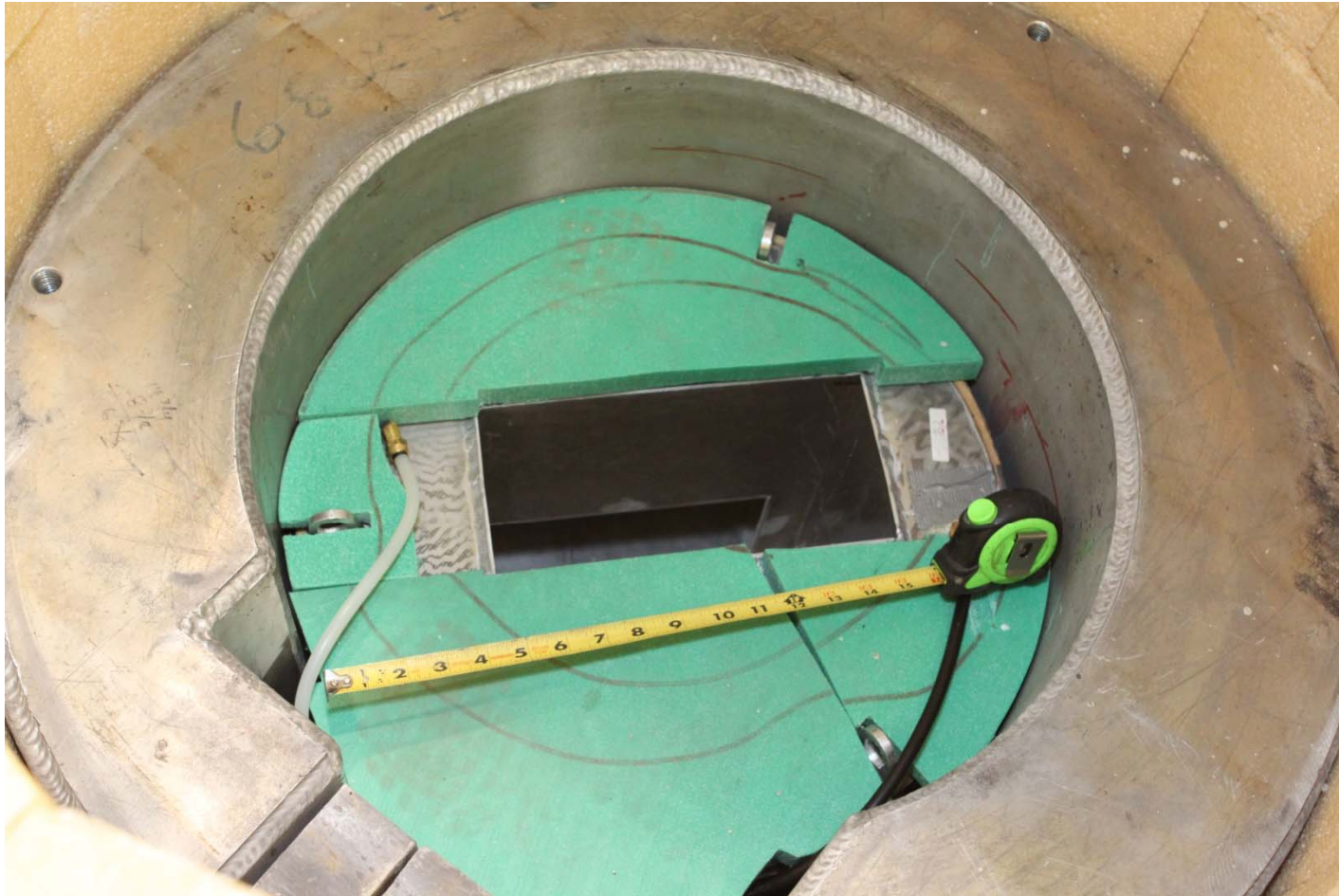
Testing IGBTs



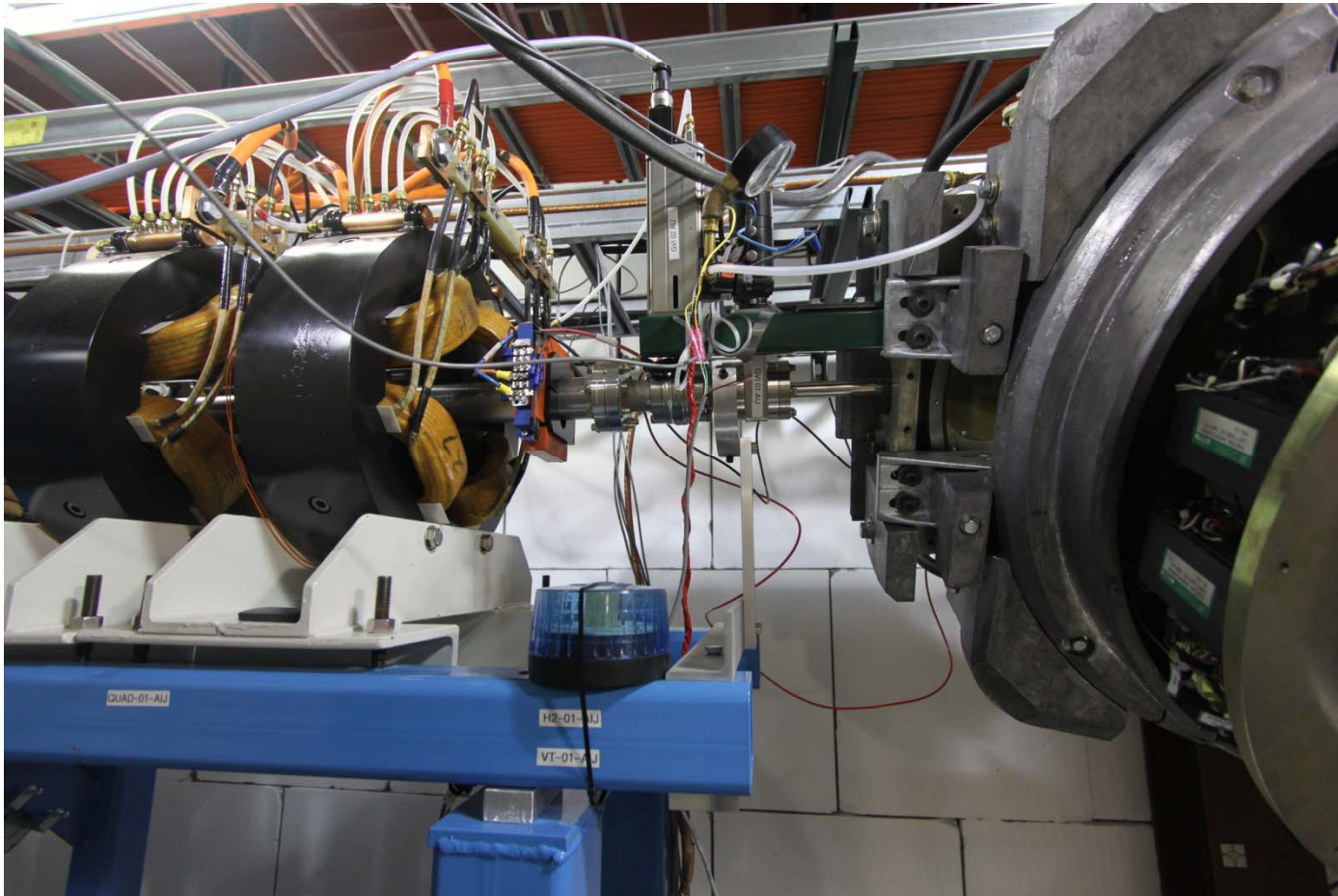
Placing a Larger Circuit Board is Problematic



The Inner Chamber could be Larger



Using the 0° Port on the Match into a Storage Ring



Recommendations

- Easy Access to test ports fast change out
- High Average beam current and Energy Tailoring
- Connections for Power and Signal Cables
- Calibration of beam energy and particle fluences
- Offer outside groups physics and testing expertise